

APT11N80KC3G

APT11N80KC3G Information

www.helsess.com	APT11N80KC3G Microsemi Corporation Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 800V 11A TO-220 TO-220-3	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com	
For Reference Only	E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



APT11N80KC3G Specifications

Manufacturer Part Number	APT11N80KC3G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	800V
Current - Continuous Drain (Id) @ 25°C	11A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.9V @ 680µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1585pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	156W (Tc)
Rds On (Max) @ Id, Vgs	450 mOhm @ 7.1A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220 [K]
Package / Case	TO-220-3
	Report errors?

APT11N80KC3G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

APT11N80KC3G Payment Methods



APT11N80KC3G Shipping Methods



If you have any question about APT11N80KC3G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com